TOSHIBA TLP701

TOSHIBA Photocoupler GaAlAs IRED + Photo IC

TLP701

Industrial inverters
Inverter for air conditioners
IGBT/Power MOS FET gate drive

TLP701 consists of a GaAlAs light-emitting diode and an integrated photodetector.

This unit is 6-lead SDIP package. The TLP701 is 50% smaller than the 8-pin DIP and meets the reinforced insulation class requirements of international safety standards. Therefore the mounting area can be reduced in equipment requiring safety standard certification.

The TLP701 is suitable for gate driving circuits for IGBTs or power MOSFETs. In particular, the TLP701 is capable of "direct" gate driving of low-power IGBTs.

Peak output current : ±0.6 A (max)
Guaranteed performance over temperature : -40 to 100°C
Supply current : 2 mA (max)
Power supply voltage : 10 to 30 V
Threshold input current : I_{FLH} = 5 mA (max)
Switching time (t_{pLH} / t_{pHL}) : 700 ns (max)
Common mode transient immunity : ±10 kV/µs (min)
Isolation voltage : 5000 Vrms (min)

· Construction mechanical rating

	7.62-mm pitch standard type	10.16-mm pitch TLPXXXF type
Creepage Distance	7.0 mm (min)	8.0 mm (min)
Clearance	7.0 mm (min)	8.0 mm (min)
Insulation Thickness	0.4 mm (min)	0.4 mm (min)

UL Recognized : UL1577, File No. E67349

Option (D4)

TÜV approved : EN60747-5-2

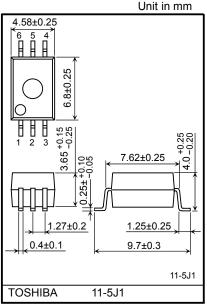
Certificate No. R50033433

Maximum operating insulation voltage : 890 Vpk Highest permissible over voltage : 8000 Vpk

(Note) When a EN60747-5-2 approved type is needed, please designate the "Option(D4)"

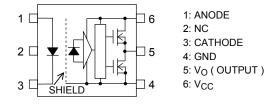
Truth Table

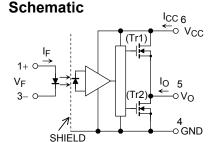
Input	LED	Tr1	Tr2	Output
Н	ON	ON	OFF	Н
L	OFF	OFF	ON	L



Weight: 0.26 g (typ.)

Pin Configuration (Top View)





A 0.1- μF bypass capacitor must be connected between pins 6 and 4. (See Note 6.)



Absolute Maximum Ratings (Ta = 25 °C)

	Characteristics			Rating	Unit
	Forward current		lF	20	mA
	Forward current derating (Ta ≥ 85°C)		ΔI _F /ΔTa	-0.54	mA/°C
LED	Peak transient forward current	(Note 1)	I _{FP}	1	Α
	Reverse voltage		V _R	5	٧
	Junction temperature		Tj	125	°C
	"H" peak output current	(Note 2)	I _{OPH}	-0.6	Α
ō	"L" peak output current		I _{OPL}	0.6	Α
Detector	Output voltage		VO	35	٧
Ď	Supply voltage		V _{CC}	35	V
	Junction temperature		Tj	125	°C
Ope	rating frequency	(Note 3)	f	25	kHz
Ope	Operating temperature range		T _{opr}	-40 to 100	°C
Storage temperature range			T _{stg}	-55 to 125	°C
Lead	Lead soldering temperature (10 s) (Note 4)		T _{sol}	260	°C
Isola	tion voltage (AC, 1 minute, R.H. ≤ 60%)	(Note 5)	BVS	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Pulse width $P_W \le 1 \mu s$, 300 pps
- Note 2: Exponential waveform pulse width $P_W \le 2 \mu s$, $f \le 15 \text{ kHz}$
- Note 3: Exponential waveform $I_{OPH} \le -0.3 \text{ A} (\le 2 \mu \text{s})$, $I_{OPL} \le +0.3 \text{ A} (\le 2 \mu \text{s})$, $T_{OPL} \le +0.3 \text{ A} (\le 2 \mu \text{s})$
- Note 4: For the effective lead soldering area
- Note 5: Device considered a two-terminal device: pins 1, 2 and 3 paired with pins 4, 5 and 6 respectively.
- Note 6: A ceramic capacitor $(0.1 \, \mu F)$ should be connected from pin 6 to pin 4 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property. The total lead length between capacitor and coupler should not exceed 1 cm.

Recommended Operating Conditions

Characteristics		Symbol	Min	Тур.	Max	Unit
Input current, ON	(Note 7)	I _{F (ON)}	7.5	_	10	mA
Input voltage, OFF		VF (OFF)	0	1	0.8	V
Supply voltage		V _{CC}	10	_	30	V
Peak output current		IOPH / IOPL	_	_	± 0.2	Α
Operating temperature		T _{opr}	-40		100	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Note 7: Input signal rise time (fall time) $< 0.5 \ \mu s.$

Electrical Characteristics (Ta = -40 to 100 °C, unless otherwise specified)

Characteristics		Symbol	Test Circuit	Test Condition		Min	Тур.*	Max	Unit
Forward voltage		V _F	_	I _F = 5 mA, Ta = 25 °C		_	1.55	1.70	V
Temperature coefficient of forward voltage		ΔV _F /ΔTa	_	I _F = 5 mA	I _F = 5 mA		-2.0	_	mV/°C
Input reverse current		I _R	_	V _R = 5 V, Ta = 25	V _R = 5 V, Ta = 25 °C		_	10	μА
Input capacitance		C _T	_	V =0 V, f = 1 MHz	, Ta = 25 °C	_	45	_	pF
	"H" Level	I _{OPH1}	1	V _{CC} = 15 V	V ₆₋₅ = 4 V	-0.2	-0.38	_	A
Output current	n Level	I _{OPH2}	'		V ₆₋₅ = 10 V	-0.4	-0.60	_	
(Note 8)	"L" Level	I _{OPL1}	2	V _{CC} = 15 V I _F = 0 mA	V ₅₋₄ = 2 V	0.2	0.36	_	
	L Levei	I _{OPL2}	2		V ₅₋₄ = 10 V	0.4	0.62	_	
	"H" Level	V _{OH}	3	V _{CC} = 10 V	$I_O = -100 \text{ mA},$ $I_F = 5 \text{ mA}$	6.0	8.5	_	<
Output voltage	"L" Level	V _{OL}	4		$I_O = 100 \text{ mA},$ $V_F = 0.8 \text{ V}$	_	0.4	1.0	
Cumply gureant	"H" Level	Icch	5	V _{CC} = 10 to 30 V	I _F = 10 mA	_	1.4	2.0	A
Supply current	"L" Level	I _{CCL}	6	V _O =Open	I _F = 0 mA	_	1.3	2.0	mA
Threshold input current	$L \rightarrow H$	I _{FLH}		V _{CC} = 15 V, V _O > 1 V		_	2.5	5	mA
Threshold input voltage	$H \rightarrow L$	V _{FHL}		V _{CC} = 15 V, V _O < 1 V		0.8	_		V
Supply voltage		Vcc	_	_	_	10	_	30	V

^{(*):} All typical values are at Ta = 25°C

Note 8: Duration of lo time \leq 50 μ s, 1 pulse

Note 9: This product is more sensitive than conventional products to electrostatic discharge (ESD) owing to its low power consumption design.

It is therefore all the more necessary to observe general precautions regarding ESD when handling this component.

Isolation Characteristics (Ta = 25 °C)

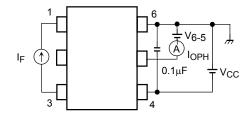
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	Cs	V = 0 V , f = 1MHz (Note 5)	_	1.0	_	pF
Isolation resistance	R _S	R.H. ≤ 60 %, V _S = 500 V (Note 5)	1×10 ¹²	10 ¹⁴	_	Ω
		AC, 1 minute	5000	_	_	Vrms
Isolation voltage	BV_S	AC, 1 second, in oil	_	10000	_	VIIIIS
		DC, 1 minute, in oil	_	10000	_	Vdc

Switching Characteristics (Ta = −40 to 100 °C, unless otherwise specified)

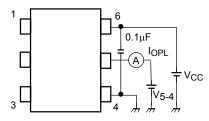
Characteristics Sym		Symbol	Test Circuit	Test Condition		Min	Тур.*	Max	Unit
Propagation delay time	$L \rightarrow H$	tpLH	 		$I_F = 0 \rightarrow 5 \text{ mA}$	100	_	700	
Tropagation delay time	$H \rightarrow L$	tpHL		$I_F = 5 \rightarrow 0 \text{ mA}$	100	_	700		
Output rise time (10-90 %)	tr			$I_F = 0 \rightarrow 5 \text{ mA}$	_	50	_	ns
Output fall time (90–10 %)		t _f		$C_g = 3 \text{ nF}$	$I_F = 5 \rightarrow 0 \text{ mA}$	_	50	_	
Switching time dispersion between ON and OFF		tрнL-tрLн	IF		I _F = 0 , 5 mA	-500	_	500	
Common mode transient i at HIGH level output	mmunity	CM _H		V _{CM} =1000 Vp-p	$I_F = 5 \text{ mA}$ $V_{O \text{ (min)}} = 26 \text{ V}$	-10000	_	_	V/µs
Common mode transient immunity at LOW level output		CML	8		$I_F = 0 \text{ mA}$ $V_{O \text{ (max)}} = 1 \text{ V}$	10000	_		V/μS

^{(*):} All typical values are at Ta = 25 °C.

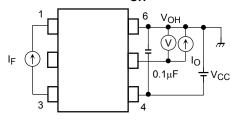
Test Circuit 1: IOPH



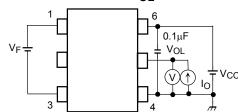
Test Circuit 2: IOPL



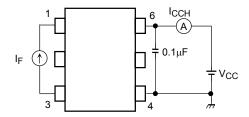
Test Circuit 3: V_{OH}



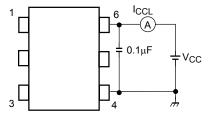
Test Circuit 4: V_{OL}



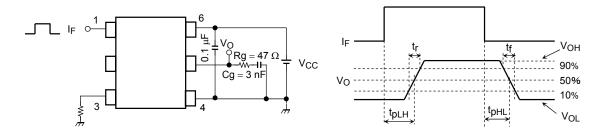
Test Circuit 5: I_{CCH}



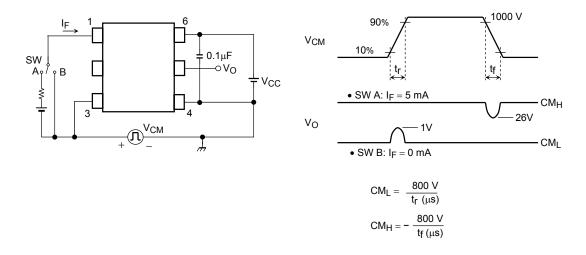
Test Circuit 6: I_{CCL}



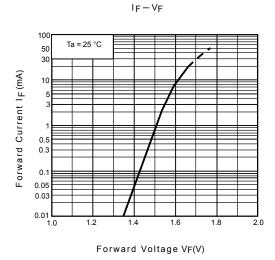
Test Circuit 7: t_{pLH}, t_{pHL}, t_r, t_f, PDD

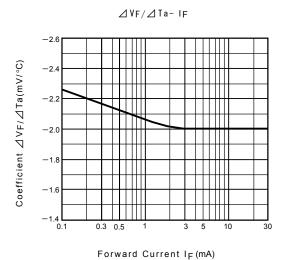


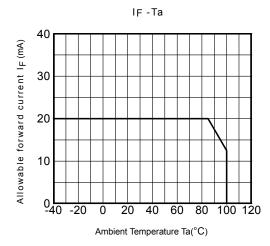
Test Circuit 8: CM_H, CM_L

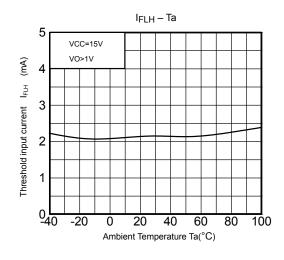


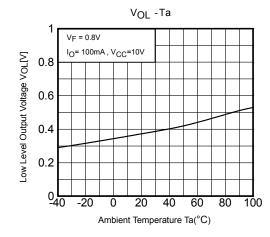
 CM_{L} (CM_H) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the LOW (HIGH) state.

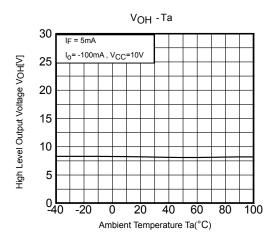






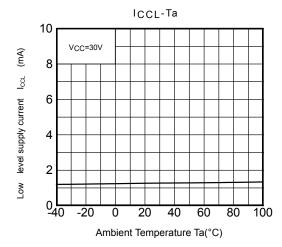


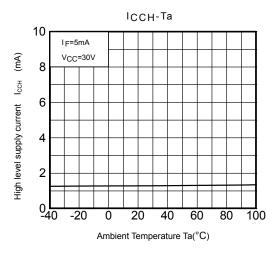


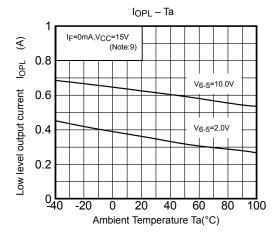


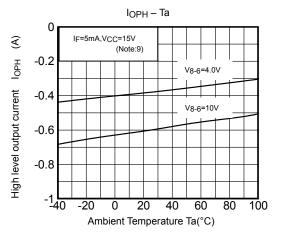
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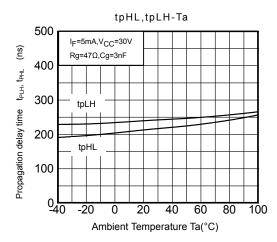
^{*:} The above graphs show typical characteristics.











 $[\]ast \vdots$ The above graphs show typical characteristics.

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